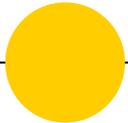




WPI

Particle Motion During Magnetron Sputter Deposition

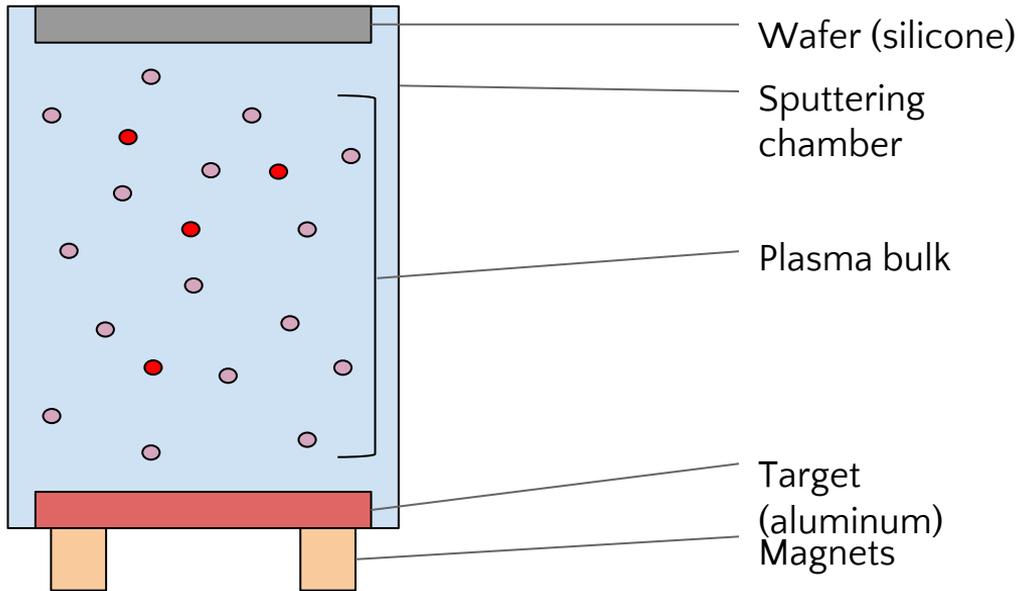


Benjamin Newmark
Kylie Sullivan

A Major Qualifying Project Submitted to the Faculty of WPI, completed in partial fulfillment of the requirements for the Degree of Bachelor of Science.



Magnetron Sputtering Deposition



What is it?

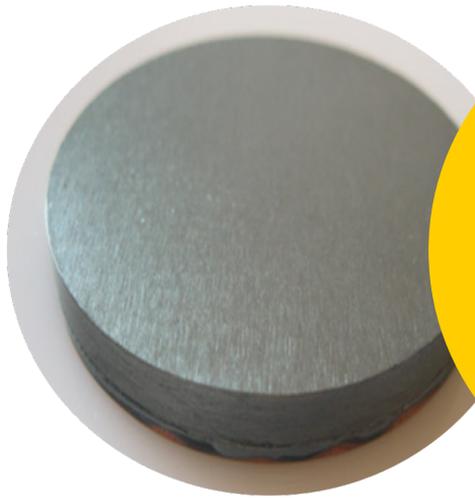
- Plasma-assisted thin film deposition technique
- Target erosion through particle bombardment

Why is it used?

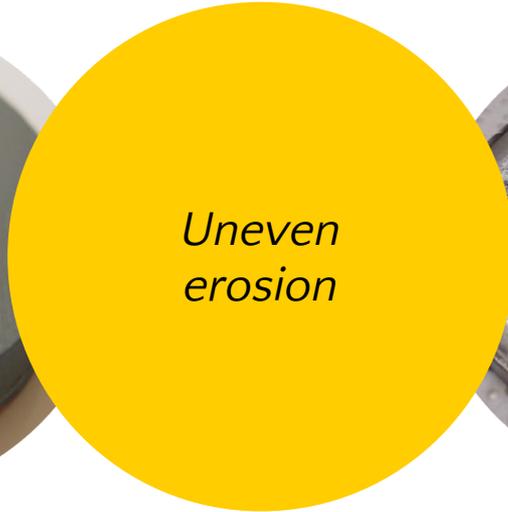
- Used for creating semiconductor materials (integrating computing chips, electron microscope slides)



Target erosion



Pre-sputtering



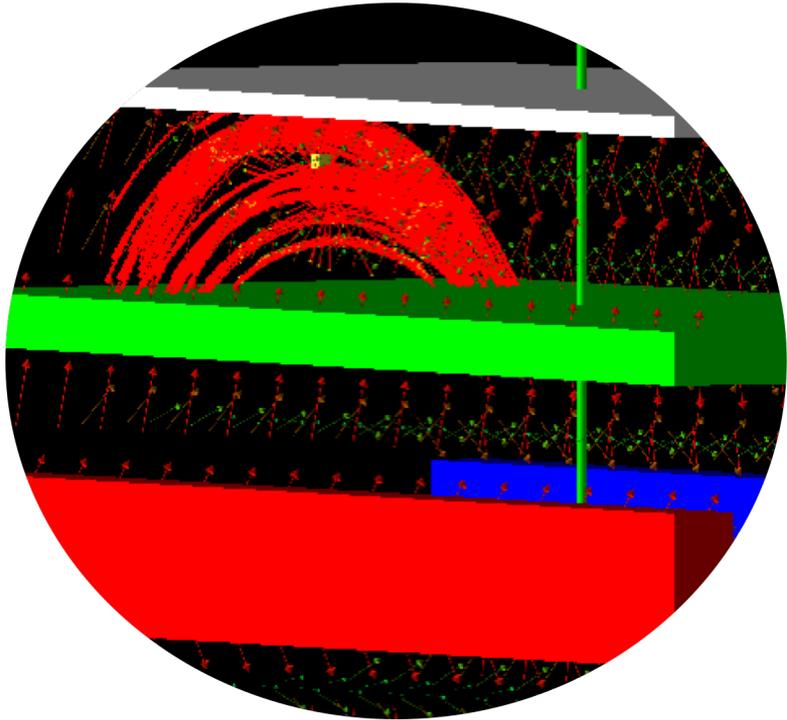
*Uneven
erosion*



Post-sputtering



Particle Motion Simulation



What could we control?

- Electron energy
- Magnetic field strength
- Electric field strength

What was native to Geant4?

- Electron motion paths

Wafer

Electron paths

Target

Magnets

Electron density simulation

x

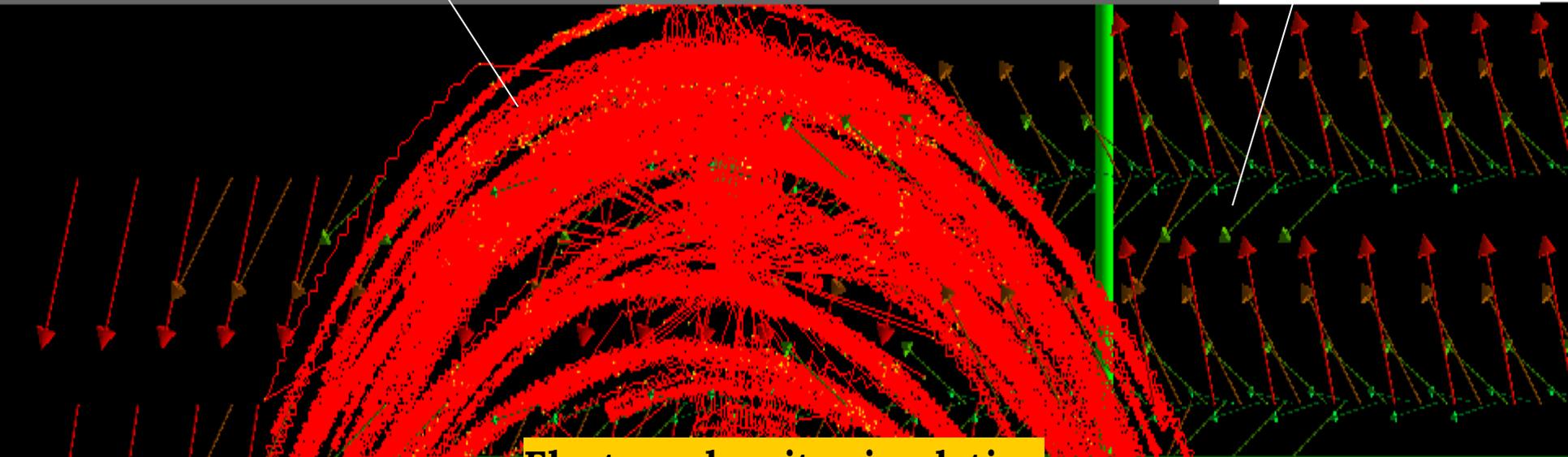
S

N

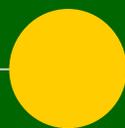
5

Electron paths

Magnetic field lines

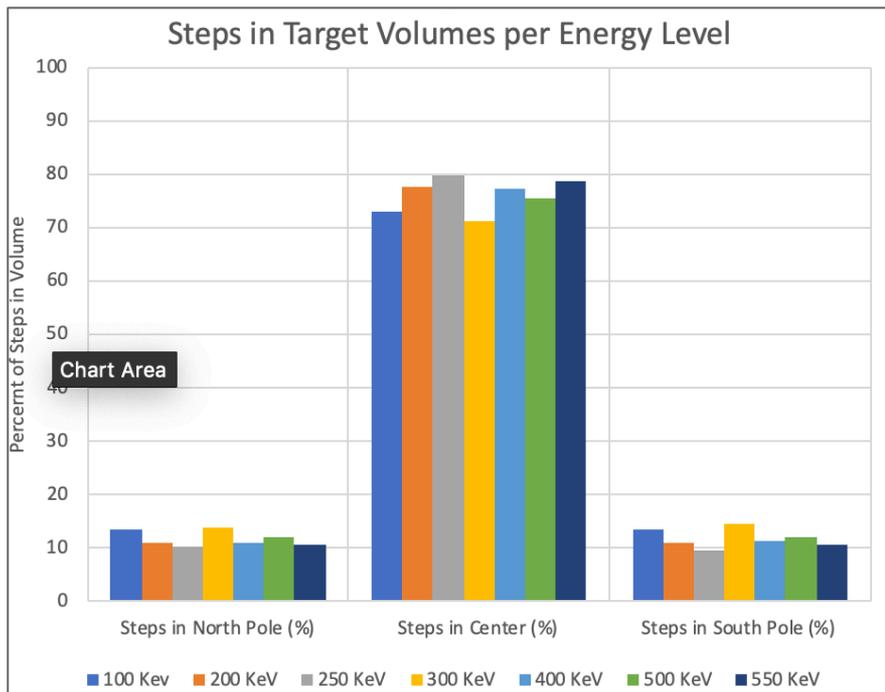


Electron density simulation





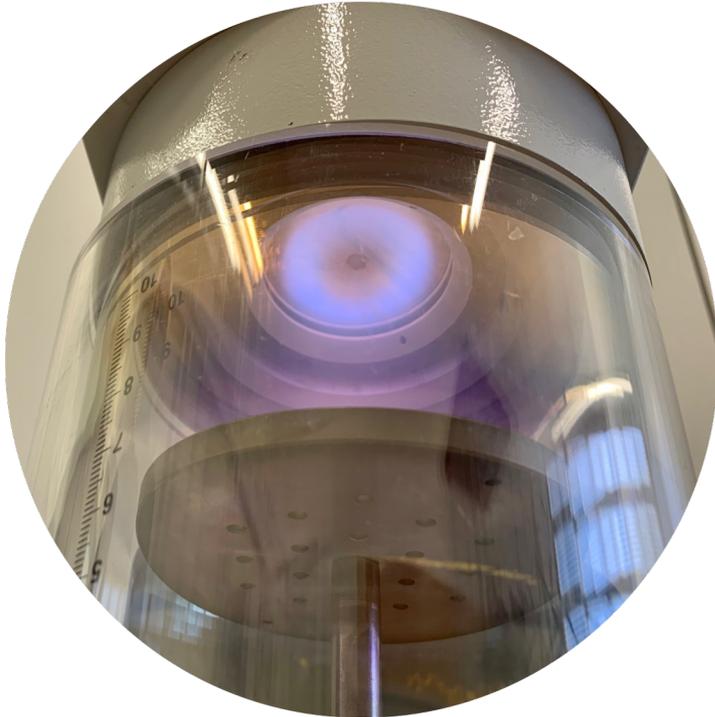
Simulation Results



Electron Energy (KeV)	Steps in North Pole (%)	Steps in Center (%)	Steps in South Pole (%)
100	13.49	72.96	13.55
200	11.21	77.66	11.13
250	10.35	79.91	9.74
300	13.87	71.38	14.75
400	11.08	77.48	11.44
500	12.14	75.70	12.16
550	10.57	78.90	10.53



Sputtering Experiments



What was done?

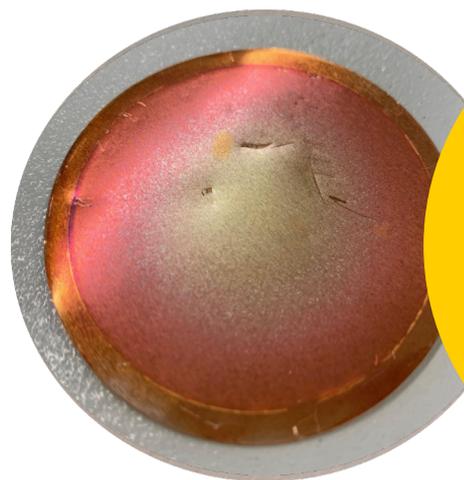
- Different targets were sputtered using a small sputtering chamber

Why were experiments conducted?

- Track how erosion patterns change based on target material
- Predict how long a target could be used before becoming over-sputtered and worn out

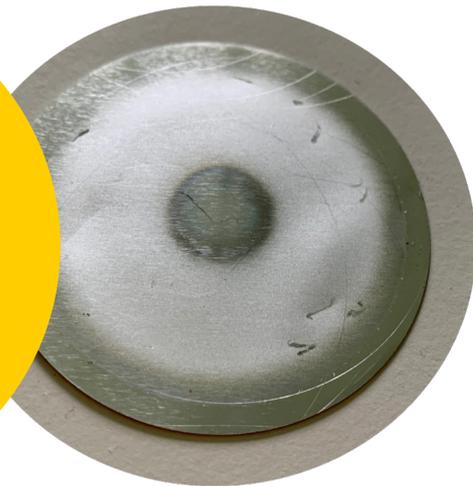


Sputtering Results



Copper target
after sputtering

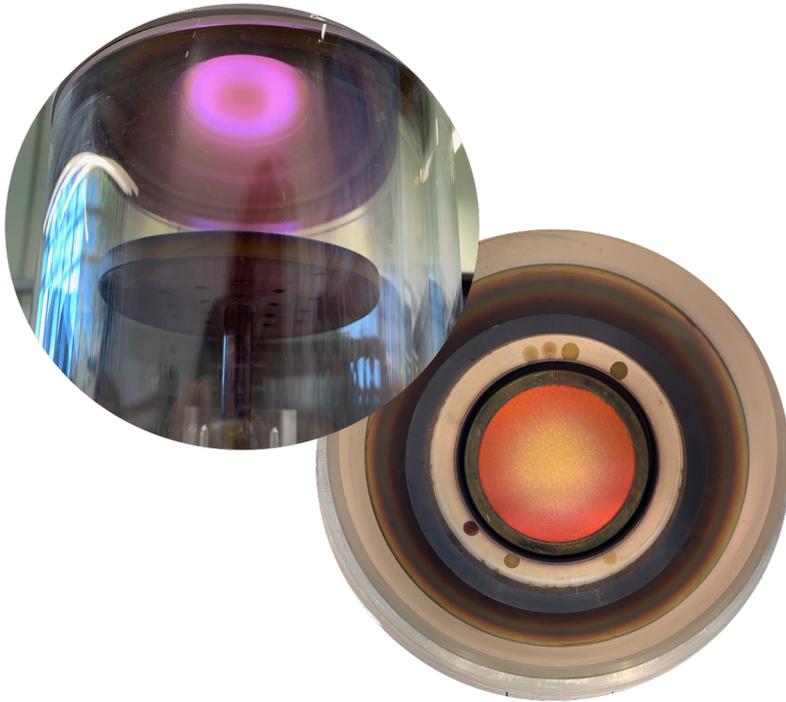
*Erosion
patterns differ
based on
material*



Aluminum target
after sputtering



Conclusions



Erosion patterns change based on:

- Particle energy
- Magnet strength/placement
- Target material

Future work:

- Use simulation to change magnet placement and strength
- Simulate ion-electron interactions
- Institute electron tracking in labs at NTB



Acknowledgements

Dr. Martin Gusche, NTB

Dr. Blake Currier, WPI

Prof. Joshua Cuneo, WPI

Dr. Eddie Schuengel, Evatec

